



YEA SHIN TECHNOLOGY CO., LTD

DTD123E

NPN Digital Transistors (Built-in Resistors)

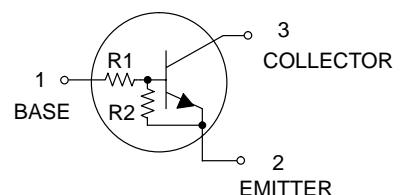
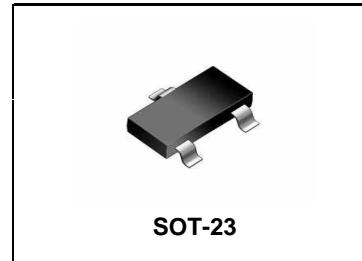


Applications

Inverter, Interface, Driver

Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
Supply voltage	V _{CC}	50		V
Input voltage	V _{IN}	-10 to +12		V
Output current	I _C	500		mA
Power dissipation	P _D	200		mW
Junction temperature	T _J	150		°C
Storage temperature	T _{STG}	-55 to +150		°C

DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
DTD123E	F22	2.2	2.2	3000/Tape & Reel

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	—	—	0.5	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	3	—	—		V _O =0.3V, I _O =20mA
Output voltage	V _{O(on)}	—	0.1	0.3	V	I _O /I _E =50mA/2.5mA
Input current	I _I	—	—	3.8	mA	V _I =5V
Output current	I _{O(off)}	—	—	0.5	μA	V _{CC} =50V, V _I =0V
DC current gain	G _I	39	—	—	—	V _O =5V, I _O =50mA
Input resistance	R _I	1.54	2.2	2.86	kΩ	—
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	—	—
Transition frequency	f _T *	—	200	—	MHz	V _{CE} =10V, I _E =-50mA, f=100MHz

*Characteristics of built-in transistor.

DEVICE CHARACTERISTICS

DTD123E

●Electrical characteristic curves

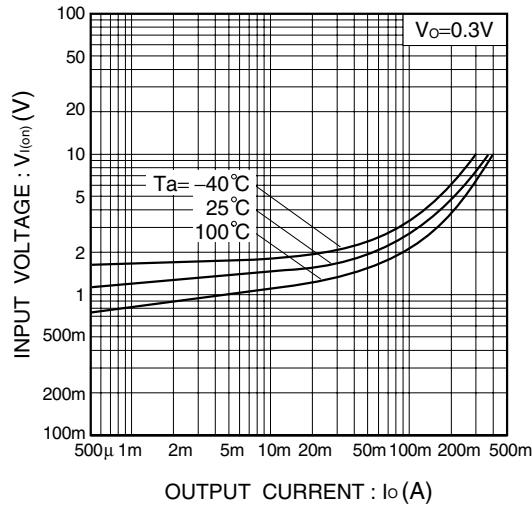


Fig.1 Input voltage vs. output current
(ON characteristics)

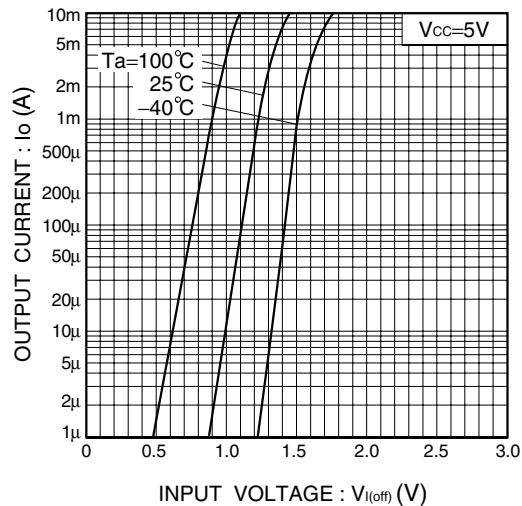


Fig.2 Output current vs. input voltage
(OFF characteristics)

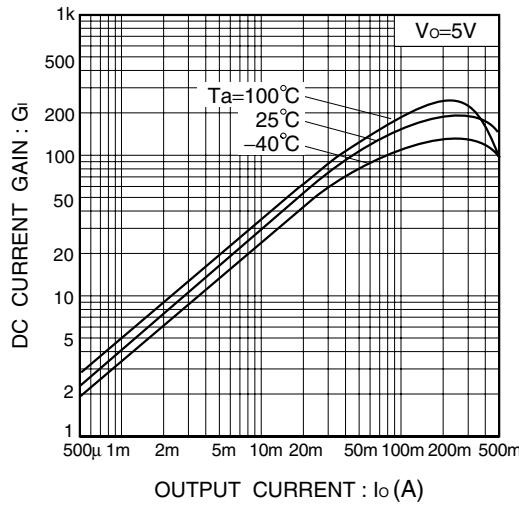


Fig.3 DC current gain
vs. output current

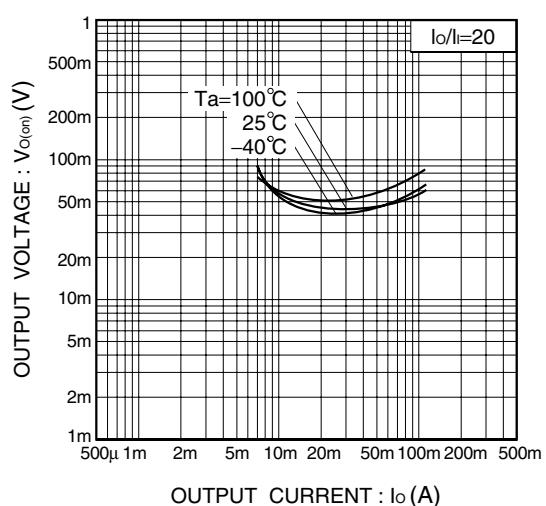


Fig.4 Output voltage vs. output current

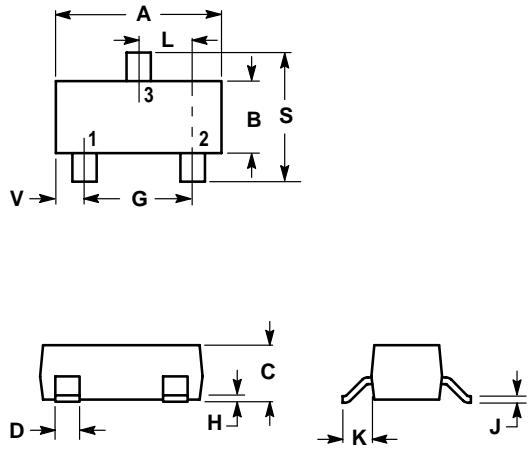
PACKAGE OUTLINE & DIMENSIONS

DTD123E

SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

